Diode Semiconductor Device - Page 1 of 1



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Inclosure Mater	
Glass and metal	
Overall Length:	
Between 0.140 i	nches and 0.180 inches
Terminal Lengt	h:
1.000 inches	
Overall Diamete	er:
Between 0.056 i	nches and 0.075 inches
Mounting Methe	od:
Terminal	
Features Provid	led:
Hermetically sea	led case and quality assurance level txv
Semiconductor	Material:
Silicon	
Voltage Rating	In Volts Per Characteristic:
75.0 regulator	voltage and 50.0 working peak reverse voltage, peak total value
Current Rating	Per Characteristic:
200.00 milliampe	eres forward current, total rms megahertz
Power Rating P	er Characteristic:
0.5 watts small-s	signal input power, common-collector preset
Maximum Oper	ating Tempurature Per Measurement Point:
200.0 degrees c	elsius ambient air
Test Data Docu	ment:
81349-mil-s-195	00 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; exclude:	s commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental a	nd performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type	And Quantity:
2 insulated wire	lead
Specification D	ata:
81349-mil-s-195	00/231 government specification
Shelf Life:	
N/a	
Unit Of Measure	e:
Demilitarization	::
No	
Fiig:	